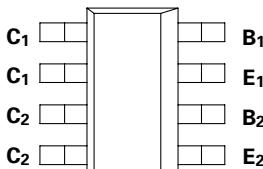


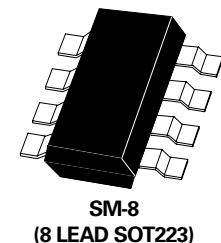
SM-8 DUAL PNP MEDIUM POWER DARLINGTON TRANSISTORS

ISSUE 1 - NOVEMBER 1995

ZDT705



PARTMARKING DETAIL – T705



ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | VALUE | UNIT |
|---|----------------|-------------|------|
| Collector-Base Voltage | V_{CBO} | -140 | V |
| Collector-Emitter Voltage | V_{CEO} | -120 | V |
| Emitter-Base Voltage | V_{EBO} | -10 | V |
| Peak Pulse Current | I_{CM} | -4 | A |
| Continuous Collector Current | I_C | -1 | A |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | -55 to +150 | °C |

THERMAL CHARACTERISTICS

| PARAMETER | SYMBOL | VALUE | UNIT |
|---|-----------|--------------|------------------|
| Total Power Dissipation at $T_{amb} = 25^\circ\text{C}^*$ Any single die "on" Both die "on" equally | P_{tot} | 2.25 2.75 | W W |
| Derate above 25°C^* Any single die "on" Both die "on" equally | | 18 22 | mW/ °C mW/ °C |
| Thermal Resistance - Junction to Ambient* Any single die "on" Both die "on" equally | | 55.6 45.5 | °C/ W °C/ W |

* The power which can be dissipated assuming the device is mounted in a typical manner on a PCB with copper equal to 2 inches square.

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ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

| PARAMETER | SYMBOL | MIN. | MAX. | UNIT | CONDITIONS. |
|---------------------------------------|----------------|----------------------|--------------|---------|---|
| Collector-Base Breakdown Voltage | $V_{(BR)CBO}$ | -140 | | V | $I_C=-100\mu A$ |
| Collector-Emitter Breakdown Voltage | $V_{CEO(SUS)}$ | -120 | | V | $I_C=-10mA^*$ |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | -10 | | V | $I_E=-100\mu A$ |
| Collector Cutoff Current | I_{CBO} | | -0.1 -10 | μA | $V_{CB}=-120V$ $V_{CB}=-120V, T_{amb}=100^\circ C$ |
| Collector Cutoff Current | I_{CES} | | -10 | μA | $V_{CE}=-80V$ |
| Emitter Cutoff Current | I_{EBO} | | -0.1 | μA | $V_{EB}=-8V$ |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | | -1.3 -2.5 | V | $I_C=1A, I_B=1mA^*$ $I_C=2A, I_B=2mA^*$ |
| Base-Emitter Saturation Voltage | $V_{BE(sat)}$ | | -1.8 | V | $I_C=1A, I_B=-10mA^*$ |
| Base-Emitter Turn-On Voltage | $V_{BE(on)}$ | | -1.7 | V | $I_C=1A, V_{CE}=-5V^*$ |
| Static Forward Current Transfer Ratio | h_{FE} | 3K 3K 3K 2K | 30K | | $I_C=10mA, V_{CE}=-5V^*$ $I_C=100mA, V_{CE}=-5V^*$ $I_C=1A, V_{CE}=-5V^*$ $I_C=2A, V_{CE}=-5V^*$ |
| Transition Frequency | f_T | | 160 Typical | MHz | $I_C=100mA, V_{CE}=-10V$ $f=20MHz$ |
| Input Capacitance | C_{ibo} | | 90 Typical | pF | $V_{EB}=-0.5V, f=1MHz$ |
| Output Capacitance | C_{obo} | | 15 Typical | pF | $V_{CE}=-10V, f=1MHz$ |
| Switching Times | t_{on} | | 0.6 Typical | μs | $I_C=0.5A, V_{CE}=-10V$ $I_{B1}=I_{B2}=-0.5mA$ |
| | t_{off} | | 0.8 Typical | μs | |

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$

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TYPICAL CHARACTERISTICS

